

SCES121F-JULY 1997-REVISED OCTOBER 2004

FE	AIURES
•	Member of the Texas Instruments Widebus™
	Family
•	EPICTM (Enhanced-Performance Implanted

- EPIC<sup>™</sup> (Enhanced-Performance Implanted CMOS) Submicron Process
- Output Port Has Equivalent 26-Ω Series Resistors, So No External Resistors Are Required
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), and Thin Very Small-Outline (DGV) Packages
- NOTE: For tape-and-reel order entry, the DGGR package is abbreviated to GR, and the DGVR package is abbreviated to VR.

## DESCRIPTION

This 18-bit universal bus driver is designed for 1.65-V to 3.6-V  $V_{\rm CC}$  operation.

Data flow from A to Y is controlled by the output-enable  $(\overline{OE})$  input. The device operates in the transparent mode when the latch-enable (LE) input is high. When LE is low, the A data is latched if the clock (CLK) input is held at a high or low logic level. If LE is low, the A data is stored in the latch/flip-flop on the low-to-high transition of CLK. When  $\overline{OE}$  is high, the outputs are in the high-impedance state.

	_		
NC	[1	$O_{56}$	GND
NC	2	55	NC
Y1	<b>[</b> ] 3	54	<b>D</b> A1
GND	4	53	GND
Y2	5	52	A2
Y3	6	51	<b>A</b> 3
$V_{CC}$	[7	50	Vcc
Y4	8 ]	49	A4
Y5	<b>[</b> 9	48	A5
Y6	10	47	A6
GND	11	46	GND
Y7	12	45	] A7
Y8	[ 13	44	A8
Y9	14	43	] A9
Y10	15	42	A10
Y11	[ 16	41	A11
Y12	[ 17	40	A12
GND	[ 18	39	]GND
Y13	[ 19	38	A13
Y14	20	37	A14
Y15	21	36	A15
V <sub>CC</sub>	22	35	Vcc
Y16	23	34	]A16
Y17	24	33	A17
GND	25	32	GND
Y18	26	31	A18
OE	27	30	]CLK
LE	28	29	] GND

DGG, DGV, OR DL PACKAGE

(TOP VIEW)

NC - No internal connection

The output port includes equivalent 26-Ω series resistors to reduce overshoot and undershoot.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74ALVCH162835 is characterized for operation from -40°C to 85°C.



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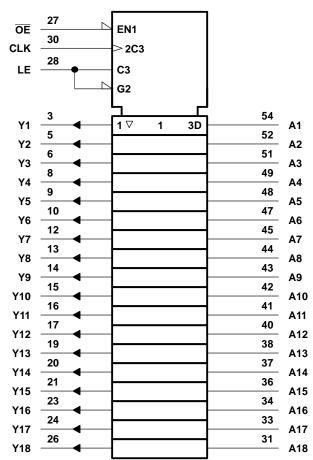
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### **FUNCTION TABLE**

	INPUTS									
ŌĒ	LE	CLK	Α	Y						
н	Х	Х	Х	Z						
L	Н	Х	L	L						
L	Н	Х	Н	н						
L	L	$\uparrow$	L	L						
L	L	$\uparrow$	Н	н						
L	L	L or H	Х	Y <sub>0</sub> <sup>(1)</sup>						

(1) Output level before the indicated steady-state input conditions were established

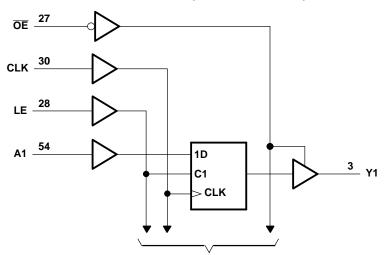


#### LOGIC SYMBOL<sup>(1)</sup>

(1) This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

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#### LOGIC DIAGRAM (POSITIVE LOGIC)



To 17 Other Channels

## **ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>**

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	4.6	V
VI	Input voltage range <sup>(2)</sup>	-0.5	4.6	V	
Vo	Output voltage range <sup>(2)(3)</sup>		-0.5	$V_{CC} + 0.5$	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>0</sub> < 0		-50	mA
lo	Continuous output current		±50	mA	
	Continuous current through each $V_{CC}$ or $GND$			±100	mA
		DGG package		81	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DGV package		86	°C/W
		DL package		74	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed. (2)

(3) (4) This value is limited to 4.6 V maximum.

The package thermal impedance is calculated in accordance with JESD 51.

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**RECOMMENDED OPERATING CONDITIONS**<sup>(1)</sup>

			MIN	MAX	UNIT		
V <sub>CC</sub>	Supply voltage		1.65	3.6	V		
		$V_{CC}$ = 1.65 V to 1.95 V	$0.65  imes V_{CC}$	$0.65  imes V_{CC}$			
V <sub>IH</sub>	High-level input voltage	$V_{CC}$ = 2.3 V to 2.7 V	1.7		V		
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2				
		$V_{CC}$ = 1.65 V to 1.95 V	0.	$35 \times V_{CC}$			
V <sub>IL</sub>	Low-level input voltage	$V_{CC}$ = 2.3 V to 2.7 V		0.7	V		
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8			
VI	Input voltage		0	V <sub>CC</sub>	V		
Vo	Output voltage		0	V <sub>CC</sub>	V		
		V <sub>CC</sub> = 1.65 V		-2			
		V <sub>CC</sub> = 2.3 V		-6			
I <sub>ОН</sub>	High-level output current	V <sub>CC</sub> = 2.7 V		-8	mA		
		$V_{CC} = 3 V$		-12			
		V <sub>CC</sub> = 1.65 V		2			
		V <sub>CC</sub> = 2.3 V		6	~ ^		
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 2.7 V		8	mA		
		$V_{CC} = 3 V$		12	2		
$\Delta t/\Delta v$	Input transition rise or fall rate			10	ns/V		
T <sub>A</sub>	Operating free-air temperature		-40	85	°C		

(1) All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP <sup>(1)</sup>	MAX	UNIT	
	I <sub>OH</sub> = -100 μA	1.65 V to 3.6 V	V <sub>CC</sub> - 0.2			
	I <sub>OH</sub> = -2 mA	1.65 V	1.2			
	I <sub>OH</sub> = -4 mA	2.3 V	1.9			
V <sub>OH</sub>		2.3 V	1.7		V	
	I <sub>OH</sub> = -6 mA	3 V	2.4			
	I <sub>OH</sub> = -8 mA	2.7 V	2			
	I <sub>OH</sub> = -12 mA	3 V	2			
	I <sub>OL</sub> = 100 μA	1.65 V to 3.6 V		0.2		
	I <sub>OL</sub> = 2 mA	1.65 V		0.45		
	$I_{OL} = 4 \text{ mA}$	2.3 V		0.4		
V <sub>OL</sub>		2.3 V		0.55	V	
	$I_{OL} = 6 \text{ mA}$	3 V		0.55		
	I <sub>OL</sub> = 8 mA	2.7 V		0.6		
	I <sub>OL</sub> = 12 mA	3 V		0.8		
I <sub>I</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.6 V		±5	μΑ	
	V <sub>I</sub> = 0.58 V	1.65 V	25			
	V <sub>I</sub> = 1.07 V	1.65 V	-25			
	V <sub>1</sub> = 0.7 V	2.3 V	45			
I <sub>I(hold)</sub>	V <sub>I</sub> = 1.7 V	2.3 V	-45		μΑ	
	V <sub>I</sub> = 0.8 V	3 V	75			
	$V_{I} = 2 V$	3 V	-75			
	$V_{I} = 0$ to 3.6 V <sup>(2)</sup>	3.6 V		±500		
I <sub>OZ</sub>	$V_{O} = V_{CC}$ or GND	3.6 V		±10	μΑ	
I <sub>CC</sub>	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	3.6 V		40	μΑ	
$\Delta I_{CC}$	One input at $V_{CC}$ - 0.6 V, Other inputs at $V_{CC}$ or GND	3 V to 3.6 V		750	μA	
Control inpu	Its V V or CND	2.2.1/	3.5		~ <b>F</b>	
C <sub>i</sub> Data inputs	$V_1 = V_{CC}$ or GND	3.3 V	6		pF	
C <sub>o</sub> Outputs	$V_{O} = V_{CC}$ or GND	3.3 V	7		pF	
. I	1	1	1			

(1) All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . (2) This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

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### TIMING REQUIREMENTS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 3)

				V <sub>CC</sub> =	1.8 V	V <sub>CC</sub> = 2 ± 0.2	2.5 V 2 V	V <sub>CC</sub> =	2.7 V	V <sub>CC</sub> = 3 ± 0.3	3.3 V 3 V	UNIT	
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
f <sub>clock</sub>	Clock frequency				(1)		150		150		150	MHz	
( Dula a duration	LE high		(1)		3.3		3.3		3.3		20		
۱w	t <sub>w</sub> Pulse duration CLK high		LK high or low			3.3		3.3		3.3		ns	
		Data before CLK↑		(1)		2.2		2.1		1.7			
t <sub>su</sub>	Setup time		CLK high	(1)		1.9		1.6		1.5		ns	
		Data before LE↓	CLK low	(1)		1.3		1.1		1			
		Data after CLK↑		(1)		0.6		0.6		0.7			
t <sub>h</sub>	Hold time	Data after LE $\downarrow$	CLK high or low	(1)		1.4		1.7		1.4		ns	

(1) This information was not available at the time of publication.

## SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 3)

PARAMETER	FROM	TO (OUTPUT)	V <sub>CC</sub> =	V <sub>CC</sub> = 1.8 V		$V_{CC}$ = 2.5 V $\pm$ 0.2 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V	
	(INPUT)	(001201)	MIN	TYP	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>max</sub>			(1)		150		150		150		MHz
	А			(1)	1	5		5	1	4.2	
t <sub>pd</sub>	LE	Y		(1)	1.3	5.9		5.8	1.3	5.1	ns
	CLK			(1)	1.4	6.3		6.1	1.4	5.4	
t <sub>en</sub>	ŌĒ	Y		(1)	1.4	6.3		6.5	1.1	5.5	ns
t <sub>dis</sub>	ŌĒ	Y		(1)	1	4.7		4.9	1.3	4.5	ns

(1) This information was not available at the time of publication.

## SWITCHING CHARACTERISTICS

from 0°C to 65°C,  $C_L = 50 \text{ pF}$ 

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 3 ± 0.15	UNIT	
		(661461)	MIN	MAX	
t <sub>pd</sub>	CLK	Y	1.9	5	ns

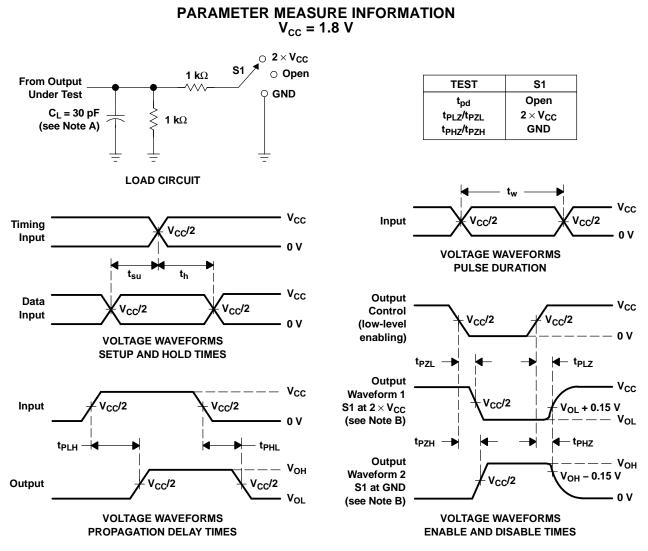
## **OPERATING CHARACTERISTICS**

 $T_A = 25^{\circ}C$ 

А								,	
	PARAMETER		TEST	CONDITIONS	V <sub>CC</sub> = 1.8 V	$V_{CC}$ = 2.5 V	$V_{CC}$ = 3.3 V	UNIT	
	PARAMETER		1531	CONDITIONS	ТҮР	TYP	TYP	UNIT	
C	Dower dissipation consultance	Outputs enabled	C = 0	f = 10 MHz	(1)	36	41	۶E	
C <sub>pd</sub>	Power dissipation capacitance	Outputs disabled	C <sub>L</sub> = 0,		(1)	12.5	14	рF	

(1) This information was not available at the time of publication.

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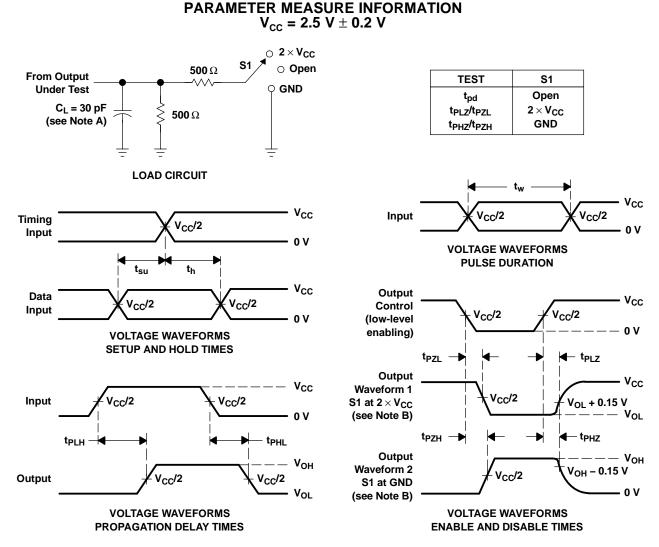


- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  2 ns, t<sub>f</sub>  $\leq$  2 ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

#### Figure 1. Load Circuit and Voltage Waveforms



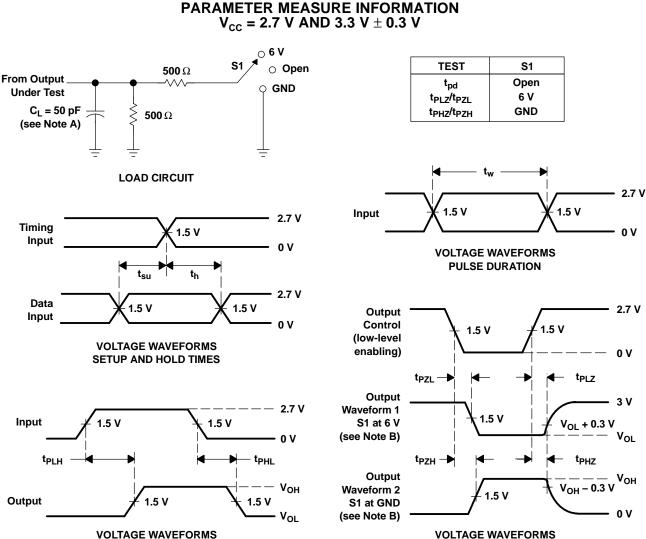
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- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2 ns, t<sub>f</sub>  $\leq$  2 ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

#### Figure 2. Load Circuit and Voltage Waveforms

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ENABLE AND DISABLE TIMES

NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

 B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>O</sub> = 50 Ω, t<sub>f</sub> ≤ 2.5 ns. t<sub>f</sub> ≤ 2.5 ns.

D. The outputs are measured one at a time, with one transition per measurement.

E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .

**PROPAGATION DELAY TIMES** 

F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .

G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 3. Load Circuit and Voltage Waveforms



11-Apr-2013

## PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
74ALVCH162835DLG4	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH162835	Samples
SN74ALVCH162835DGGR	OBSOLETE	TSSOP	DGG	56		TBD	Call TI	Call TI	-40 to 85		
SN74ALVCH162835DGVR	OBSOLETE	TVSOP	DGV	56		TBD	Call TI	Call TI	-40 to 85		
SN74ALVCH162835DL	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH162835	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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# **MECHANICAL DATA**

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

## DGV (R-PDSO-G\*\*)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
  - This drawing is subject to change without notice. В.
  - Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15). C.
  - D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.



# **MECHANICAL DATA**

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

### DGG (R-PDSO-G\*\*)

### PLASTIC SMALL-OUTLINE PACKAGE

**48 PINS SHOWN** 



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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